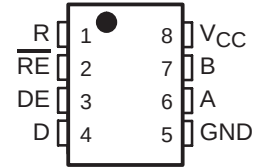


- **Controlled Baseline**
 - One Assembly/Test Site, One Fabrication Site
- **Extended Temperature Performance of** -40°C to 125°C and -55°C to 125°C
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product Change Notification**
- **Qualification Pedigree[†]**
- **High-Speed Low-Power LinBiCMOS[™] Circuitry Designed for Signaling Rates[‡] Up to 30 Mbps**
- **Bus-Pin ESD Protection Exceeds 12-kV HBM**
- **Compatible With ANSI Standard TIA/EIA-485-A and ISO 8482:1987(E)**
- **Low Skew**
- **Designed for Multipoint Transmission on Long Bus Lines in Noisy Environments**
- **Low Disabled Supply Current Requirements . . . 700 μA Maximum**
- **Common-Mode Voltage Range of -7 V to 12 V**
- **Thermal-Shutdown Protection**
- **Driver Positive and Negative Current Limiting**
- **Open-Circuit Fail-Safe Receiver Design**
- **Receiver Input Sensitivity . . . $\pm 200\text{ mV}$ Max**
- **Receiver Input Hysteresis . . . 50 mV Typ**
- **Glitch-Free Power-Up and Power-Down Protection**

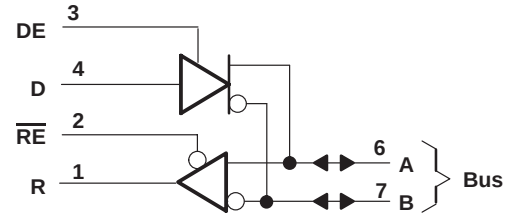
[†] Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

[‡] Signaling rate by TIA/EIA-485-A definition restrict transition times to 30% of the bit length, and much higher signaling rates may be achieved without this requirement as displayed in the *TYPICAL CHARACTERISTICS* of this device.

**D Package
(TOP VIEW)**



logic diagram (positive logic)



Function Tables

DRIVER

INPUT D	ENABLE DE	OUTPUTS	
		A	B
H	H	H	L
L	H	L	H
X	L	Z	Z
Open	H	H	L

RECEIVER

DIFFERENTIAL INPUTS $V_A - V_B$	ENABLE $\overline{\text{RE}}$	OUTPUT R
$V_{ID} \geq 0.2\text{ V}$	L	H
$-0.2\text{ V} < V_{ID} < 0.2\text{ V}$	L	?
$V_{ID} \leq -0.2\text{ V}$	L	L
X	H	Z
Open	L	H

H = high level, L = low level, ? = indeterminate,
X = irrelevant, Z = high impedance (off)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinBiCMOS and LinASIC are trademarks of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

Copyright © 2004, Texas Instruments Incorporated

SN65LBC176A-EP

DIFFERENTIAL BUS TRANSCEIVER

SGLS151C – DECEMBER 2002 – REVISED JULY 2004

description/ordering information

The SN65LBC176A-EP differential bus transceiver is a monolithic, integrated circuits designed for bidirectional data communication on multipoint bus-transmission lines. The SN65LBC176A-EP is designed for balanced transmission lines and is compatible with ANSI standard TIA/EIA-485-A and ISO 8482. The SN65LBC176A-EP offers improved switching performance over its predecessors without sacrificing significantly more power.

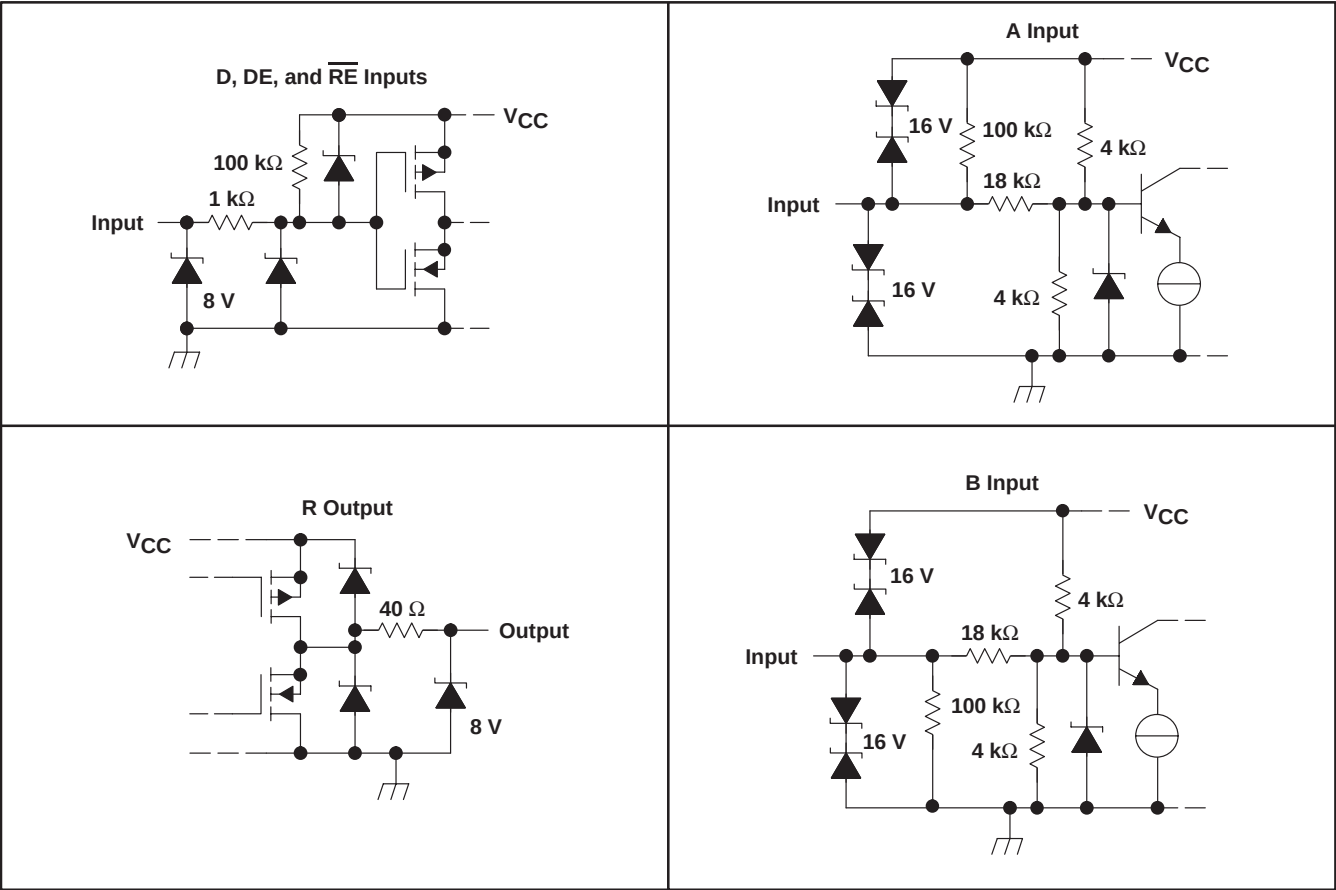
The SN65LBC176A-EP combines a 3-state, differential line driver and a differential input line receiver, both of which operate from a single 5-V power supply. The driver and receiver have active-high and active-low enables, respectively, which can externally connect together to function as a direction control. The driver differential outputs and the receiver differential inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus whenever the driver is disabled or $V_{CC} = 0$. This port features wide positive and negative common-mode voltage ranges, making the device suitable for party-line applications. Low device supply current can be achieved by disabling the driver and the receiver.

ORDERING INFORMATION

TA	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 125°C	SOIC – D	Tape and Reel	SN65LBC176AQDREP	176AEP
–55°C to 125°C	SOIC – D	Tape and Reel	SN65LBC176AMDREP	176MEP

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

schematics of inputs and outputs



absolute maximum ratings[†]

Supply voltage, V_{CC} (see Note 1)	–0.3 V to 6 V
Voltage range at any bus terminal (A or B)	–10 V to 15 V
Input voltage, V_I (D, DE, R, or $\overline{RE}$)	–0.3 V to $V_{CC} + 0.5$ V
Electrostatic discharge: Bus terminals and GND, Class 3, A: (see Note 2)	12 kV
Bus terminals and GND, Class 3, B: (see Note 2)	400 V
All terminals, Class 3, A:	4 kV
All terminals, Class 3, B:	400 V
Continuous total power dissipation (see Note 3)	See Dissipation Rating Table
Storage temperature range, T_{stg} (see Note 4)	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

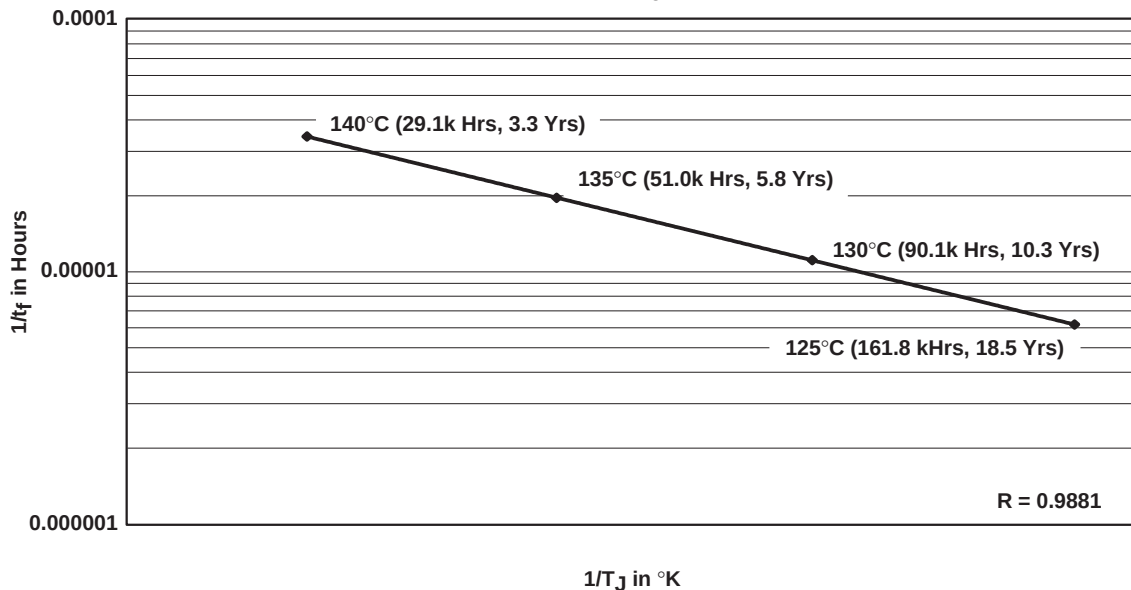
- NOTES:
1. All voltage values, except differential I/O bus voltage, are with respect to network ground terminal.
 2. The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature.
 3. Tested in accordance with MIL-STD-883C, Method 3015.7
 4. Long-term, high-temperature storage and/or extended use at maximum recommended operating conditions may result in a reduction of overall device life. See http://www.ti.com/ep_quality for additional information on enhanced plastic packaging.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR [‡] ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW

[‡] This is the inverse of the junction-to-ambient thermal resistance when the board is mounted and with no air flow.

OPERATING LIFE DERATING TABLE – SN65LBC176AMDREP
 $1/t_f$ vs $1/T_J$ in °K



- NOTES:
- A. See the data sheet for absolute maximum and maximum recommended operating conditions.
 - B. Silicon operating life design goal is 10 years at 105°C junction temperature (does not include package interconnect life).
 - C. Attached enhanced plastic product disclaimer applies.

SN65LBC176A-EP

DIFFERENTIAL BUS TRANSCEIVER

SGLS151C – DECEMBER 2002 – REVISED JULY 2004

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		4.75	5	5.25	V
Voltage at any bus terminal (separately or common mode), V _I or V _{IC}		12			V
		−7			
High-level input voltage, V _{IH} (output recessive)	D, DE, and $\overline{RE}$	2		V _{CC}	V
Low-level input voltage, V _{IL} (output dominant)	D, DE, and $\overline{RE}$	0		0.8	V
Differential input voltage, V _{ID} (see Note 5)		−12 [§]		12	V
High-level output current, I _{OH}	Driver	−60			mA
	Receiver	−8			
Low-level output current, I _{OL}	Driver			60	mA
	Receiver			8	
Operating free-air temperature, T _A	SN65LBC176AQ-EP	−40		125	°C
	SN65LBC176AM-EP	−55		125	

[§] The algebraic convention, in which the least positive (most negative) limit is designated as minimum, is used in this data sheet.

NOTE 5: Differential input/output bus voltage is measured at the noninverting terminal A with respect to the inverting terminal B.

driver electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
V_{IK} Input clamp voltage	$I_I = -18$ mA	-1.5	-0.8		V
$ V_{OD} $ Differential output voltage	$I_O = 0$	1.5	4	6	V
	$R_L = 54 \Omega$, See Figure 1	0.9	1.5	6	
	$V_{test} = -7$ V to 12 V, See Figure 2	0.9	1.5	6	
$\Delta V_{OD} $ Change in magnitude of differential output voltage	See Figure 1 and Figure 2	-0.2		0.2	V
$V_{OC(SS)}$ Steady-state common-mode output voltage	See Figure 1	1.8	2.4	3	V
$\Delta V_{OC(SS)}$ Change in steady-state common-mode output voltage [†]	See Figure 1	-0.2		0.2	V
I_{OZ} High-impedance output current	See receiver input currents				
I_{IH} High-level enable input current	$V_I = 2$ V	-100			μ A
I_{IL} Low-level enable input current	$V_I = 0.8$ V	-100			μ A
I_{OS} Short-circuit output current	-7 V $\leq V_O \leq 12$ V	-250	± 70	250	mA
I_{CC} Supply current	$V_I = 0$ or V_{CC} , No load	Receiver disabled and driver enabled		5	mA
		Receiver disabled and driver disabled		0.4	
		Receiver enabled and driver enabled		8.5	

[†] All typical values are at $V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

driver switching characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t _{PLH} Propagation delay time, low-to-high level output	R _L = 54 Ω, C _L = 50 pF, See Figure 3	2		12	ns
t _{PHL} Propagation delay time, high-to-low level output		2		12	
t _{sk(p)} Pulse skew (t _{PLH} – t _{PHL})				2	
t _r Differential output signal rise time		1.2		11	
t _f Differential output signal fall time		1.2		11	
t _{PZH} Propagation delay time, high-impedance to high-level output	R _L = 110 Ω, See Figure 4			22	ns
t _{PZL} Propagation delay time, high-impedance to low-level output	R _L = 110 Ω, See Figure 5			25	ns
t _{PHZ} Propagation delay time, high-level to high-impedance output	R _L = 110 Ω, See Figure 4			22	ns
t _{PLZ} Propagation delay time, low-level to high-impedance output	R _L = 110 Ω, See Figure 5			22	ns

† All typical values are at V_{CC} = 5 V, T_A = 25°C.

receiver electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
V _{IT+} Positive-going input threshold voltage	I _O = –8 mA			0.2	V
V _{IT–} Negative-going input threshold voltage	I _O = 8 mA	–0.2			V
V _{hys} Hysteresis voltage (V _{IT+} – V _{IT–})			50		mV
V _{IK} Enable-input clamp voltage	I _I = –18 mA	–1.5	–0.8		V
V _{OH} High-level output voltage	V _{ID} = 200 mV, I _{OH} = –8 mA, See Figure 6	4	4.9		V
V _{OL} Low-level output voltage	V _{ID} = 200 mV, I _{OL} = 8 mA, See Figure 6		0.1	0.8	V
I _{OZ} High-impedance-state output current	V _O = 0 to V _{CC}	–10		10	μA
I _I Bus input current	V _{IH} = 12 V, V _{CC} = 5 V	Other input at 0 V	0.4	1	mA
	V _{IH} = 12 V, V _{CC} = 0		0.5	1	
	V _{IH} = –7 V, V _{CC} = 5 V		–0.8	–0.4	
	V _{IH} = –7 V, V _{CC} = 0		–0.8	–0.3	
I _{IH} High-level enable-input current	V _{IH} = 2 V	–100			μA
I _{IL} Low-level enable-input current	V _{IL} = 0.8 V	–100			μA
I _{CC} Supply current	V _I = 0 or V _{CC} , No load	Receiver enabled and driver disabled	4	7	mA
		Receiver disabled and driver disabled	0.4	0.7	
		Receiver enabled and driver enabled	8.5	15	

† All typical values are at V_{CC} = 5 V, T_A = 25°C.

SN65LBC176A-EP

DIFFERENTIAL BUS TRANSCEIVER

SGLS151C – DECEMBER 2002 – REVISED JULY 2004

receiver switching characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
t_{PLH} Propagation delay time, output $\uparrow$	$V_{ID} = -1.5\text{ V to }1.5\text{ V}$, See Figure 7	7		30	ns
t_{PHL} Propagation delay time, output $\downarrow$		7		30	ns
$t_{sk(p)}$ Pulse skew ($ t_{PHL} - t_{PLH} $)				6	ns
t_r Rise time, output	See Figure 7			5	ns
t_f Fall time, output				5	ns
t_{PZH} Output enable time to high level	$C_L = 10\text{ pF}$, See Figure 8			50	ns
t_{PZL} Output enable time to low level				50	ns
t_{PHZ} Output disable time from high level				60	ns
t_{PLZ} Output disable time from low level				40	ns

[†] All typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.

PARAMETER MEASUREMENT INFORMATION

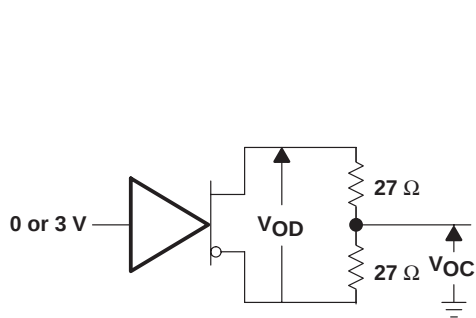


Figure 1. Driver V_{OD} and V_{OC}

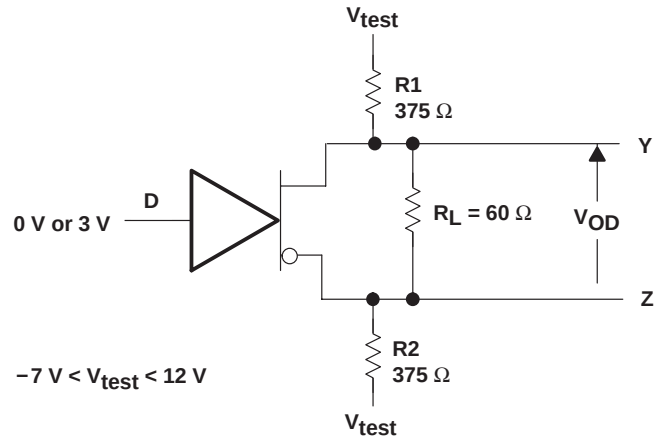
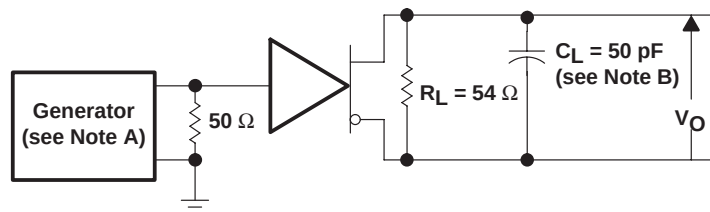
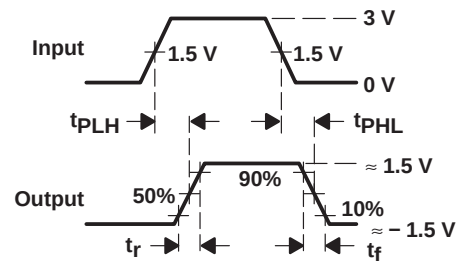


Figure 2. Driver V_{OD3}



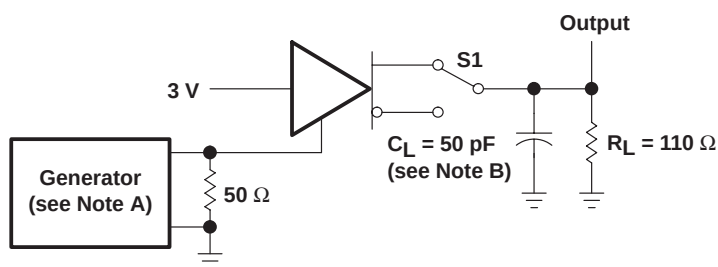
TEST CIRCUIT



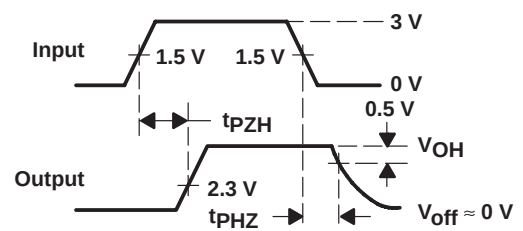
VOLTAGE WAVEFORMS

- NOTES: D. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1$ MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.
E. C_L includes probe and jig capacitance.

Figure 3. Driver Test Circuit and Voltage Waveforms



TEST CIRCUIT



VOLTAGE WAVEFORMS

- NOTES: A. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1$ MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.
B. C_L includes probe and jig capacitance.

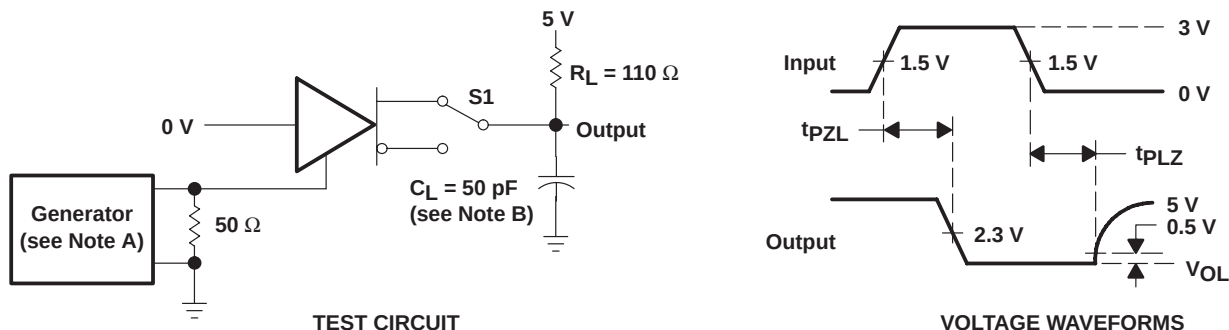
Figure 4. Driver Test Circuit and Voltage Waveforms

SN65LBC176A-EP

DIFFERENTIAL BUS TRANSCEIVER

SGLS151C – DECEMBER 2002 – REVISED JULY 2004

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: $\text{PRR} \leq 1\ \text{MHz}$, 50% duty cycle, $t_r \leq 6\ \text{ns}$, $t_f \leq 6\ \text{ns}$, $Z_O = 50\ \Omega$.
B. C_L includes probe and jig capacitance.

Figure 5. Driver Test Circuit and Voltage Waveforms

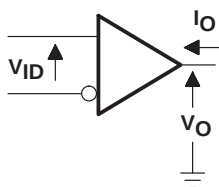
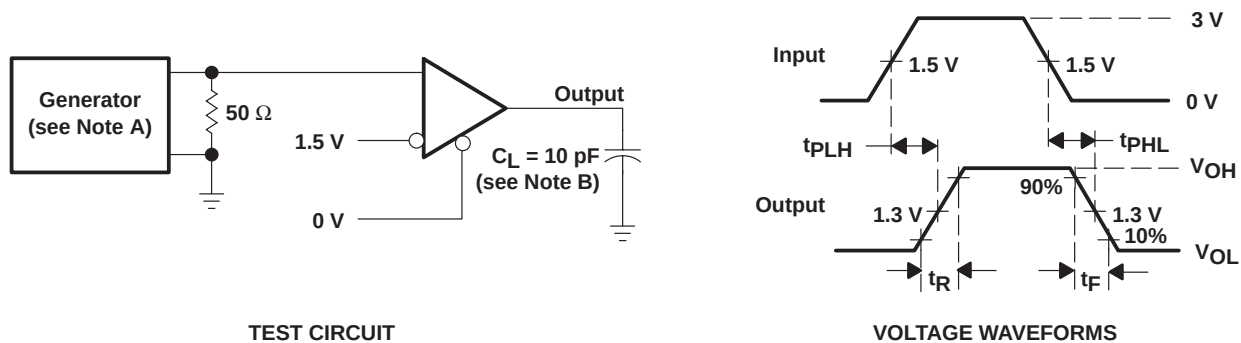


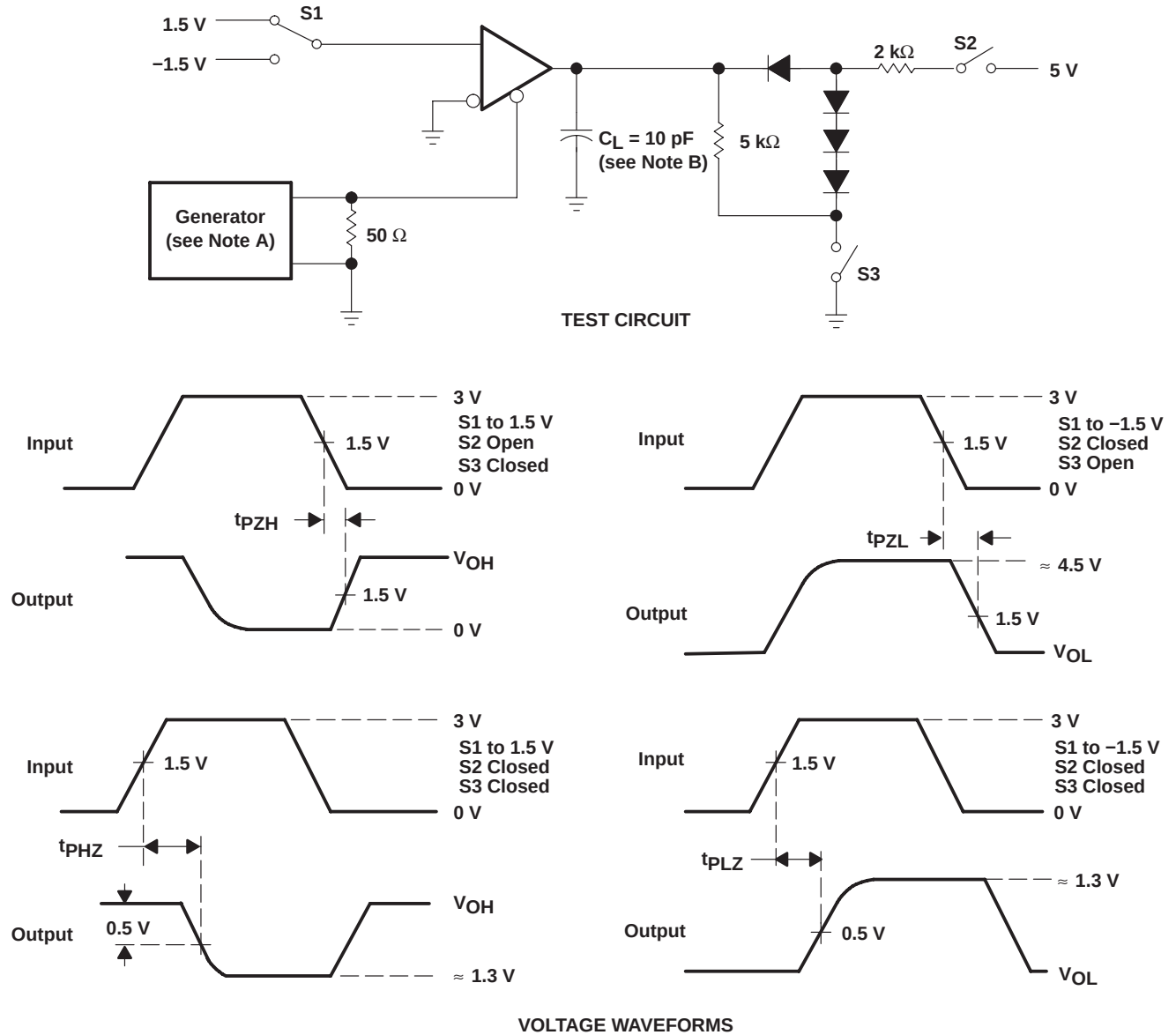
Figure 6. Receiver V_{OH} and V_{OL}



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: $\text{PRR} \leq 1\ \text{MHz}$, 50% duty cycle, $t_r \leq 6\ \text{ns}$, $t_f \leq 6\ \text{ns}$, $Z_O = 50\ \Omega$.
B. C_L includes probe and jig capacitance.

Figure 7. Receiver Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR $\leq$ 1 MHz, 50% duty cycle, $t_r \leq$ 6 ns, $t_f \leq$ 6 ns, $Z_O = 50 \Omega$.
- B. C_L includes probe and jig capacitance.

Figure 8. Receiver Test Circuit and Voltage Waveforms

SN65LBC176A-EP

DIFFERENTIAL BUS TRANSCEIVER

SGLS151C – DECEMBER 2002 – REVISED JULY 2004

TYPICAL CHARACTERISTICS

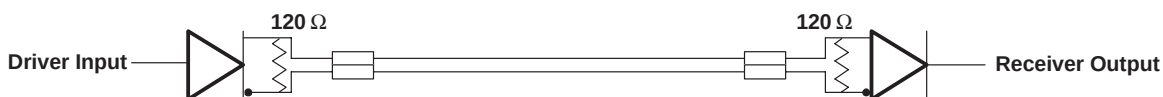
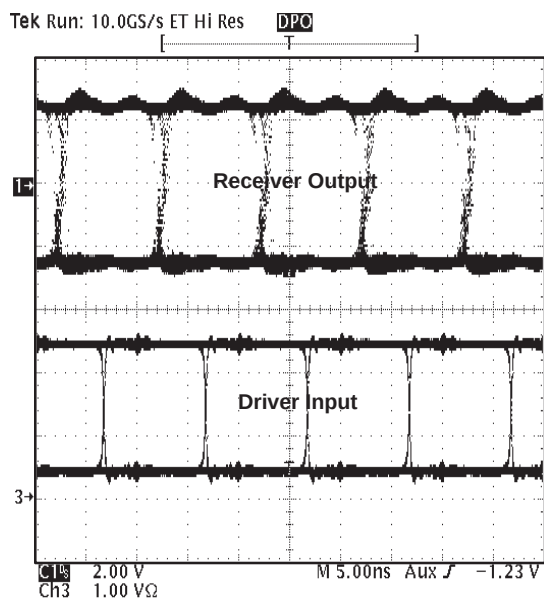


Figure 9. Typical Waveform of Non-Return-To-Zero (NRZ), Pseudorandom Binary Sequence (PRBS) Data at 100 Mbps Through 15m, of CAT 5 Unshielded Twisted Pair (UTP) Cable

TIA/EIA-485-A defines a maximum signaling rate as that in which the transition time of the voltage transition of a logic-state change remains less than or equal to 30% of the bit length. Transition times of greater length perform quite well, even though they do not meet the standard by definition.

TYPICAL CHARACTERISTICS

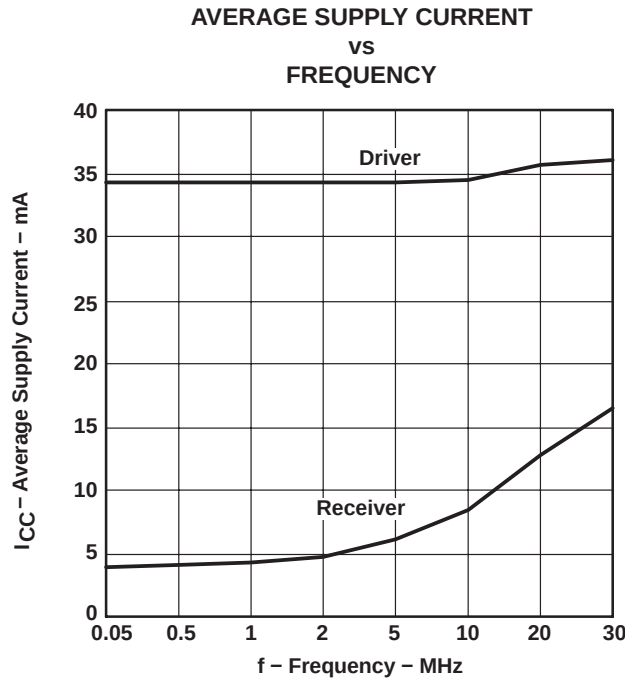


Figure 10

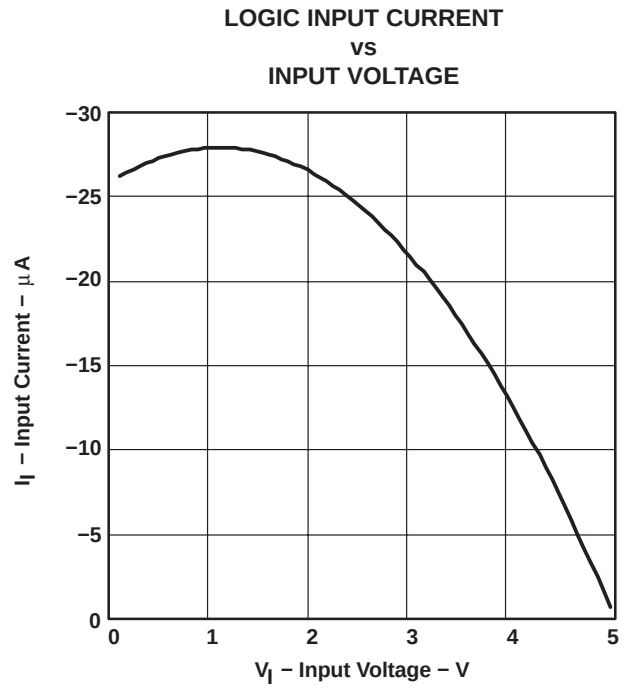


Figure 11

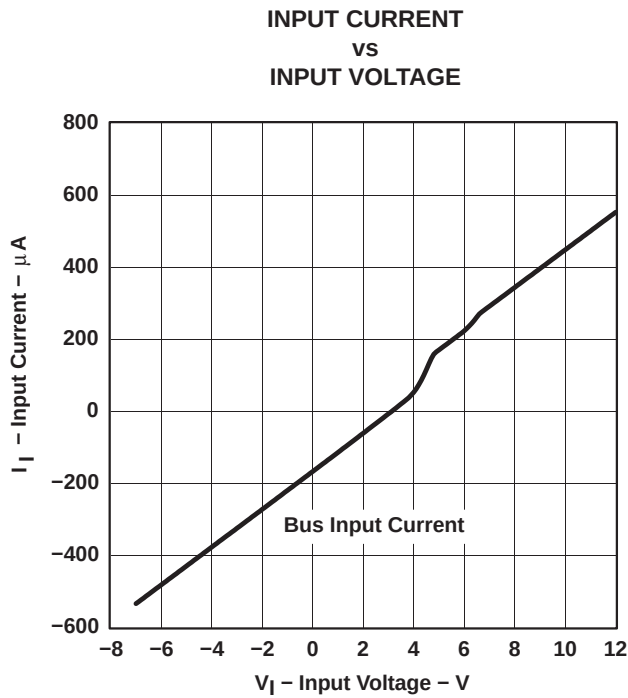


Figure 12

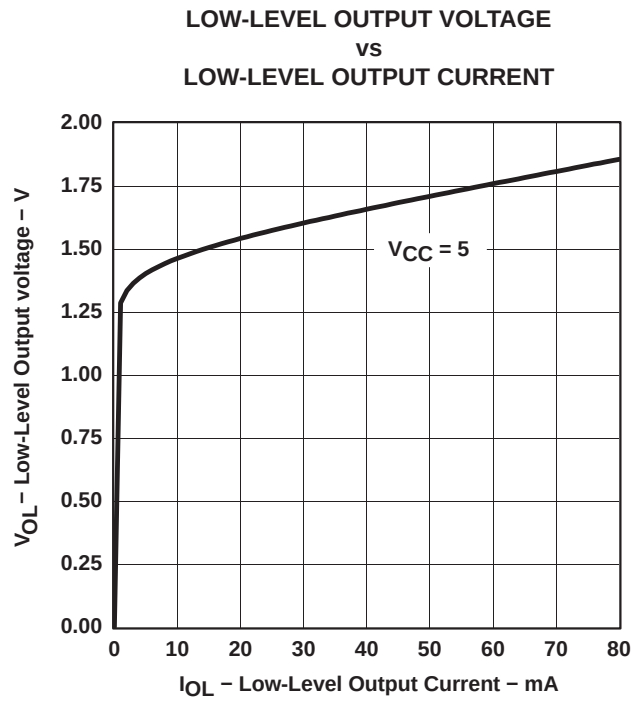


Figure 13

SN65LBC176A-EP
DIFFERENTIAL BUS TRANSCEIVER

SGLS151C – DECEMBER 2002 – REVISED JULY 2004

TYPICAL CHARACTERISTICS

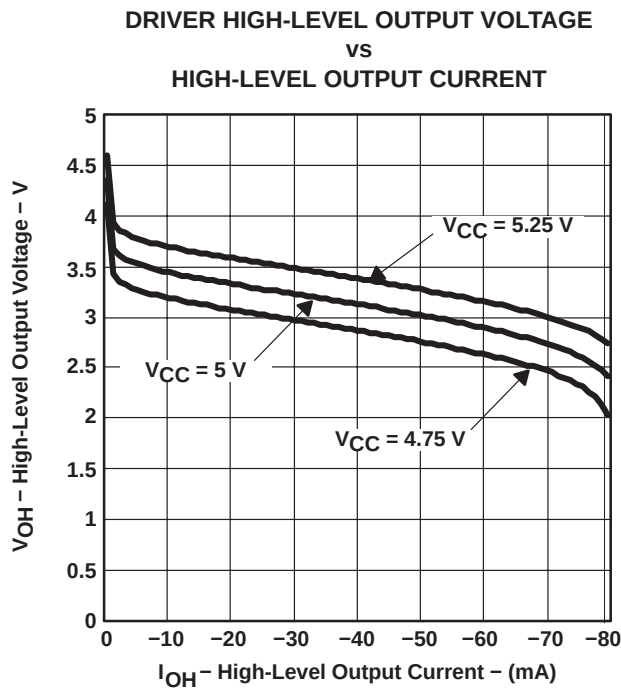


Figure 14

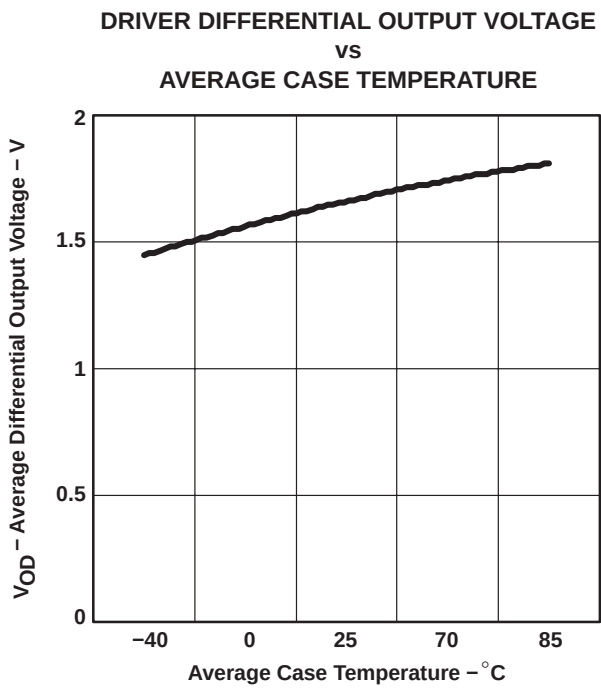


Figure 15

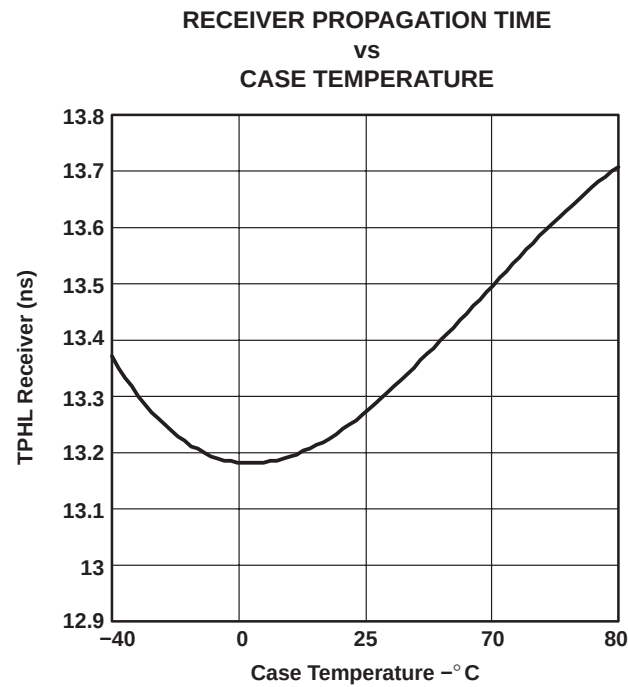


Figure 16

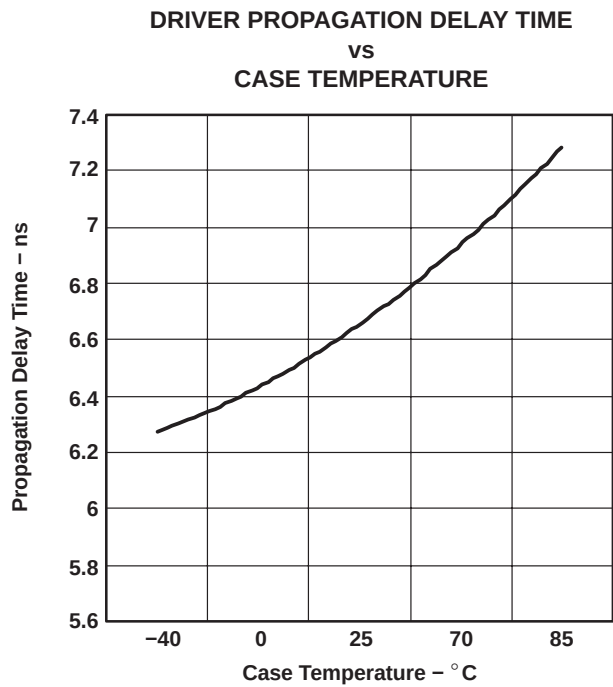


Figure 17

TYPICAL CHARACTERISTICS

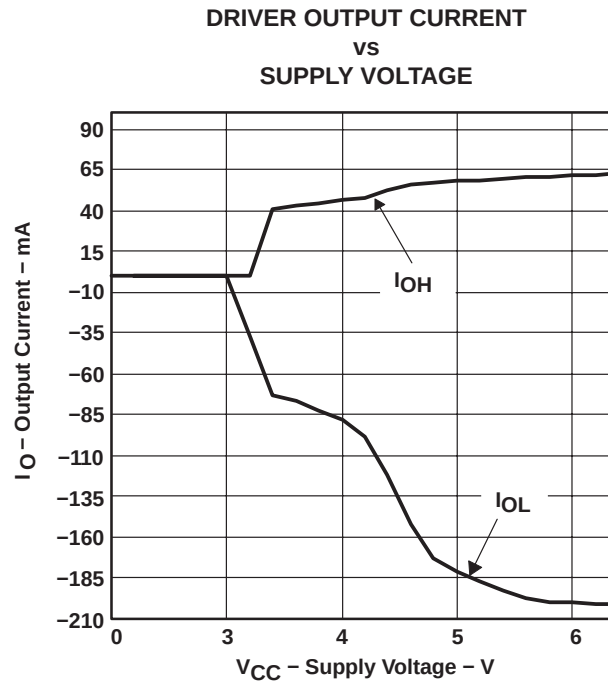


Figure 18

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN65LBC176AMDREP	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	176MEP
SN65LBC176AMDREP.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	176MEP
SN65LBC176AQDREP	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	176AEP
SN65LBC176AQDREP.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	176AEP
V62/03671-01XE	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	176AEP
V62/03671-02XE	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	176MEP

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

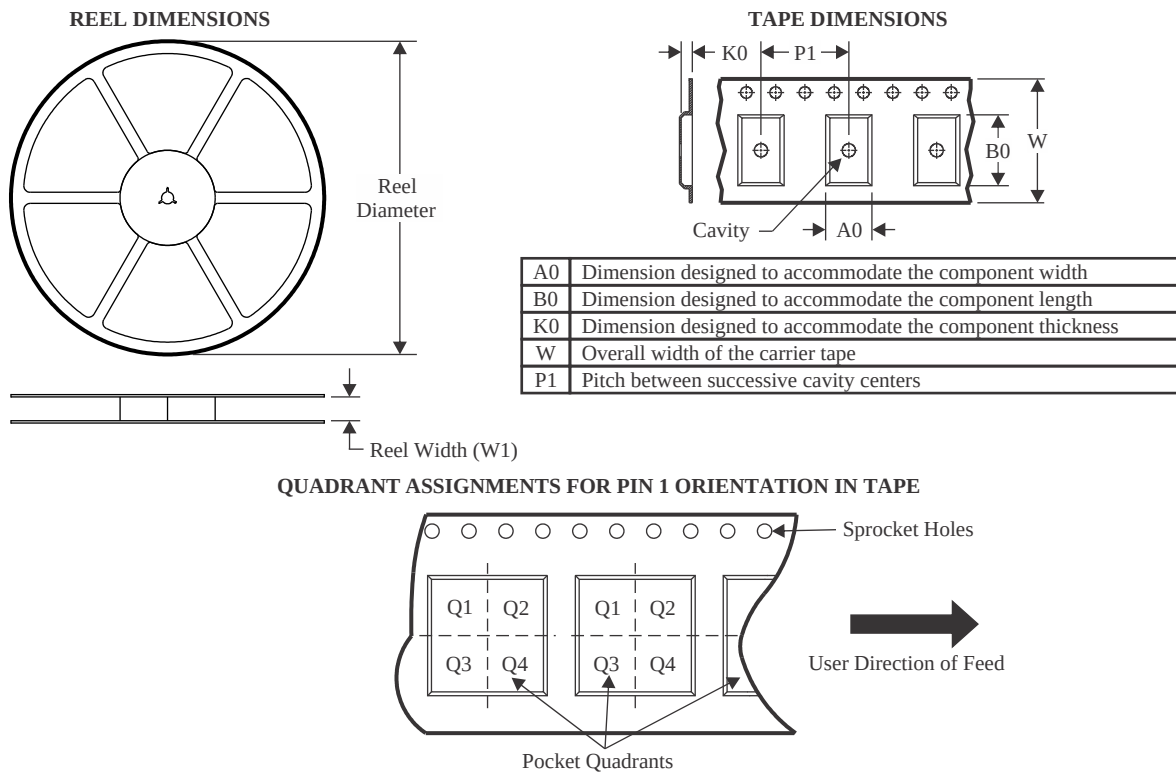
OTHER QUALIFIED VERSIONS OF SN65LBC176A-EP :

- Catalog : [SN65LBC176A](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

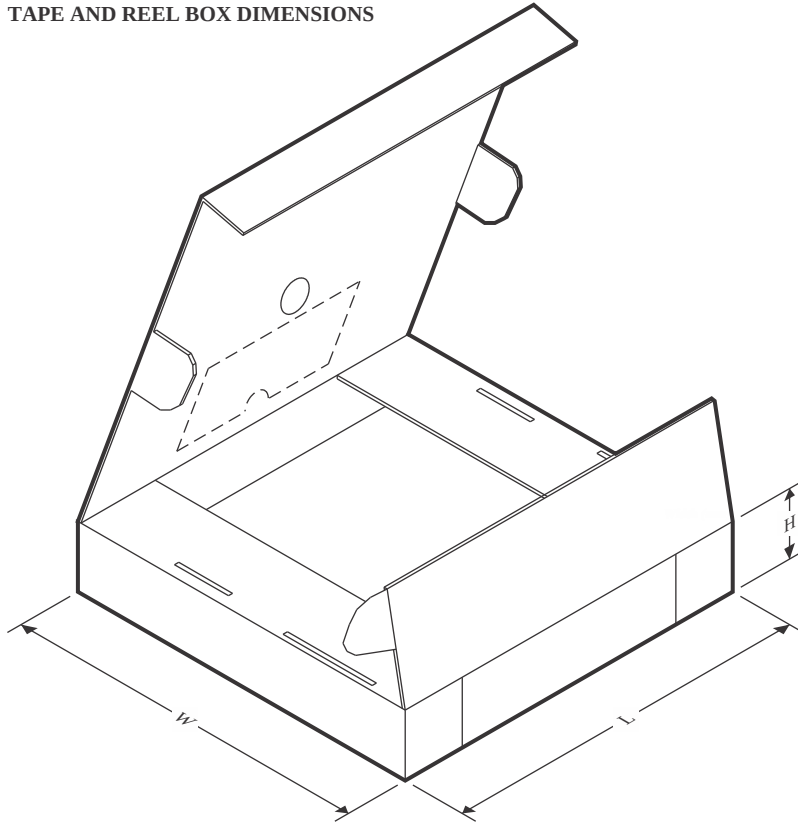
TAPE AND REEL INFORMATION



*All dimensions are nominal

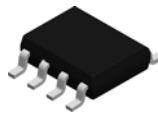
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC176AMDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN65LBC176AQDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC176AMDREP	SOIC	D	8	2500	350.0	350.0	43.0
SN65LBC176AQDREP	SOIC	D	8	2500	350.0	350.0	43.0

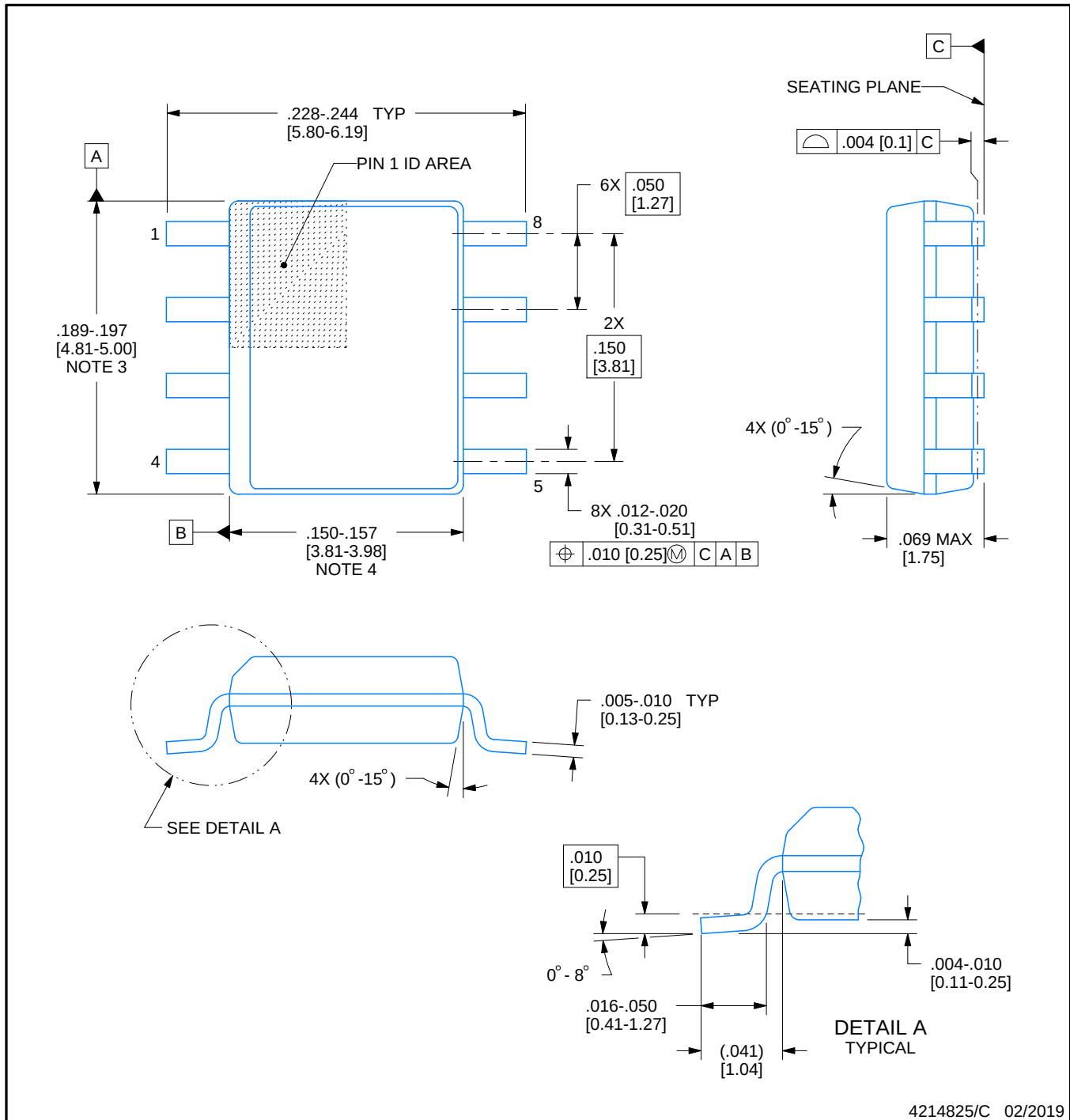


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

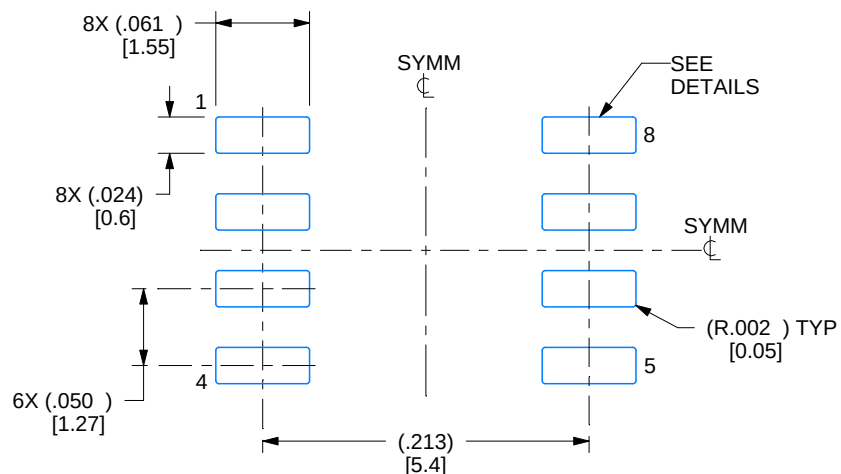
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

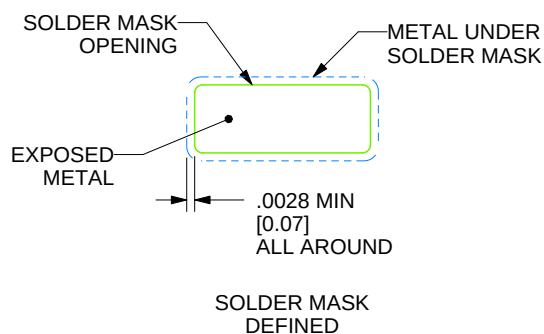
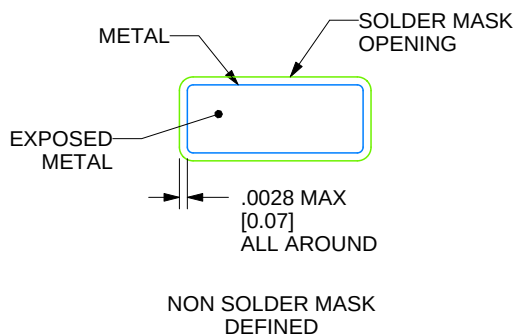
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

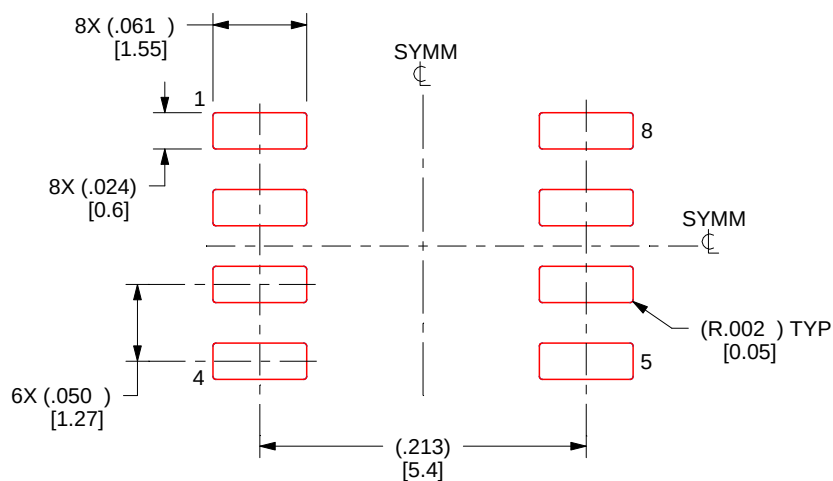
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2025, Texas Instruments Incorporated